

LMV821-Q1 LMV822-Q1 LMV824-Q1

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SLOS461F-MARCH 2005-REVISED JULY 2010

LOW-VOLTAGE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS

Check for Samples: LMV821-Q1, LMV822-Q1, LMV824-Q1

FEATURES

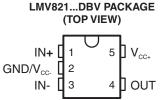
- Qualified for Automotive Applications
- 2.5-V, 2.7-V, and 5-V Performance
- -40°C to 125°C Operation
- No Crossover Distortion
- Low Supply Current at V_{CC+} = 5 V
 - LMV821: 0.3 mA Typ
 - LMV822: 0.5 mA Typ
 - LMV824: 1 mA Typ
- Rail-to-Rail Output Swing
- Gain Bandwidth of 5.5 MHz Typ at 5 V
- Slew Rate of 1.9 V/µs Typ at 5 V

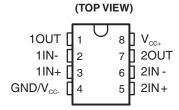
DESCRIPTION/ORDERING INFORMATION

The LMV821 single, LMV822 dual, and LMV824 quad devices are low-voltage (2.5 V to 5.5 V), low-power commodity operational amplifiers. Electrical characteristics are very similar to the LMV3xx operational amplifiers (low supply current, rail-to-rail outputs, input common-mode range that includes ground). However, the LMV82x devices offer a higher bandwidth (5.5 MHz typical) and faster slew rate (1.9 V/µs typical).

The LMV82x devices are cost-effective solutions for applications requiring low-voltage/low-power operation and space-saving considerations. The LMV821 saves space on printed circuit boards and enables the design of small portable electronic devices (cordless and cellular phones, laptops, PDAs, PCMIA). It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

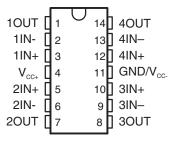
The LMV82x devices are characterized for operation from –40°C to 125°C.





LMV822...DGK PACKAGE

LMV824...D OR PW PACKAGE (TOP VIEW)



ORDERING INFORMATION(1)

T _A		PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING (3)
	Single	SOT-23 – DBV	Reel of 3000	LMV821QDBVRQ1	RB1_
40°C to 125°C	Dual	MSOP/VSSOP - DGK	Reel of 2500	LMV822QDGKRQ1	R8B
–40°C to 125°C	Quad	SOIC - D	Reel of 2500	LMV824QDRQ1	LMV824Q
	Quad	TSSOP - PW	Reel of 2000	LMV824QPWRQ1	MV824Q

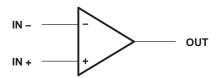
- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (3) DBV: The actual top-side marking has one additional character that designates the wafer fab/assembly site.



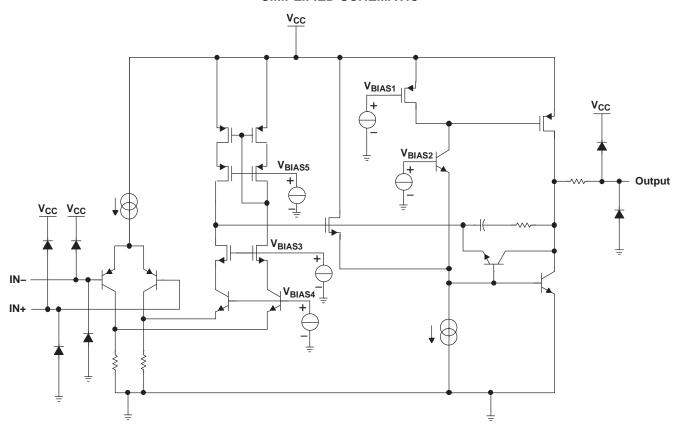
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SYMBOL (EACH AMPLIFIER)



SIMPLIFIED SCHEMATIC





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ABSOLUTE MAXIMUM RATINGS(1)

STRUMENTS

over operating free-air temperature range (unless otherwise noted)

	peraurig nee an temperature range (amose entermee net	/				
V_{CC}	Supply voltage (2)		5.5 V			
V_{ID}	Differential input voltage (3)		±V _{CC}			
V_{I}	Input voltage range (either input)	ut voltage range (either input)				
	Duration of output short circuit (one amplifier) to ground (4)	At or below $T_A = 25$ °C, $V_{CC} \le 5.5 \text{ V}$	Unlimited			
		D package	97°C/W			
0	Dealer and the arrest increased are as (5), (6)	DBV package	206°C/W			
θ_{JA}	Package thermal impedance (5) (6)	DGK package	172°C/W			
		PW package	113°C/W			
T_{J}	Operating virtual-junction temperature		150°C			
T _{stg}	Storage temperature range		−65°C to 150°C			

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.
- (5) Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V_{CC}	Supply voltage (single-supply operation)	2.5	5	V
T _A	Operating free-air temperature	-40	125	°C

2.5-V ELECTRICAL CHARACTERISTICS

 $V_{CC+} = 2.5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 1 \text{ V}$, $V_{O} = 1.25 \text{ V}$, and $R_{I} > 1 \text{ M}\Omega$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		T _A	MIN	TYP	MAX	UNIT
V	Input offeet voltege		25°C		1	6	mV	
V _{IO}	Input offset voltage			-40°C to 125°C			6	IIIV
			Liab laval	25°C	2.28	2.37		
		V 25 V D 600 O to 4.25 V	High level	-40°C to 125°C	2.18			1
		$V_{CC+} = 2.5 \text{ V}, R_L = 600 \Omega \text{ to } 1.25 \text{ V}$	Low level	25°C		0.13	0.22	
V	Output awing			-40°C to 125°C			0.32	
Vo	Output swing			25°C	2.38	2.46		V
			High level	-40°C to 125°C	2.28			
		$V_{CC+} = 2.5 \text{ V}, R_L = 2 \text{ k}\Omega \text{ to } 1.25 \text{ V}$	Lavulaval	25°C		0.08	0.14	
			Low level	-40°C to 125°C			0.22	



2.7-V ELECTRICAL CHARACTERISTICS

 V_{CC+} = 2.7 V, V_{CC-} = 0 V, V_{IC} = 1 V, V_{O} = 1.35 V, and R_L > 1 M Ω (unless otherwise noted)

	PARAMETER	TEST CONDIT	IONS	T _A	MIN	TYP	MAX	UNIT	
V _{IO}	Input offset voltage			25°C		1	6	mV	
v IO	input onset voltage			-40°C to 125°C			6	1117	
α_{VIO}	Average temperature coefficient of input offset voltage			25°C		1		μV/°C	
ı	Innut high ourrent			25°C		30	90	~ ^	
l _{IB}	Input bias current			-40°C to 125°C			140	nA	
	lanut affact ourrant			25°C		0.5	30	~ ^	
10	Input offset current			-40°C to 125°C			50	nA	
CMDD	Common mode rejection ratio	\/ 0 to 1 7 \/		25°C	70	85		٩D	
JWKK	Common-mode rejection ratio	$V_{IC} = 0 \text{ to } 1.7 \text{ V}$		-40°C to 125°C	68			dB	
. 1.	Positive supply-voltage	$V_{CC+} = 1.7 \text{ V to 4 V, } V_{CC}$	_ = -1 V,	25°C	75	85		٦D	
+k _{SVR}	rejection ratio	$V_{O} = 0, V_{IC} = 0$		-40°C to 125°C	70			dB	
1.	Negative supply-voltage	$V_{CC+} = 1.7 \text{ V}, V_{CC-} = -1$	V to -3.3 V,	25°C	73	85		٦D	
–k _{SVR}	rejection ratio	$V_O = 0$, $V_{IC} = 0$	•	-40°C to 125°C	70			dB	
V _{ICR}	Common-mode input voltage range	CMRR ≥ 50 dB		25°C	-0.2 to 1.9	-0.3 to 2		V	
		$R_L = 600 \Omega \text{ to } 1.35 \text{ V},$	Coursing	25°C	90	100			
		$V_0 = 1.35 \text{ V to } 2.2 \text{ V}$	Sourcing	-40°C to 125°C	85			- dB	
		$R_L = 600 \Omega \text{ to } 1.35 \text{ V},$	Cialia a	25°C	85	90			
^	Lanca di mala militari	$V_0 = 1.35 \text{ V to } 0.5 \text{ V}$	Sinking	-40°C to 125°C	80				
A_{\bigvee}	Large-signal voltage amplification	$R_L = 2 k\Omega \text{ to } 1.35 \text{ V},$ $V_O = 1.35 \text{ V to } 2.2 \text{ V}$ $R_I = 2 k\Omega \text{ to } 1.35 \text{ V},$	0	25°C	95	100			
			Sourcing	-40°C to 125°C	90				
			Sinking	25°C	90	95			
		$V_0 = 1.35 \text{ V to } 0.5 \text{ V}$ Sinking		-40°C to 125°C	85			ĺ	
				25°C	2.5	2.58			
		$V_{CC+} = 2.7 \text{ V},$	High level	-40°C to 125°C	2.4				
		$R_L = 600 \Omega \text{ to } 1.35 \text{ V}$	Laurianal	25°C		0.13	0.2		
,	Outract and a		Low level	-40°C to 125°C			0.3	.,	
√ _O	Output swing		I Park Laurah	25°C	2.6	2.66		V	
		$V_{CC+} = 2.7 \text{ V},$	High level	-40°C to 125°C	2.5				
		$R_L = 2 k\Omega \text{ to } 1.35 \text{ V}$	11	25°C		0.08	0.12		
			Low level	-40°C to 125°C			0.2		
	Output surrent	V _O = 0 V	Sourcing	25°C	12	16		^	
0	Output current	V _O = 2.7 V	Sinking	25°C	12	26		mA	
		LM\/004	•	25°C		0.22	0.3		
		LMV821		-40°C to 125°C			0.5		
	Complex assument	LMV/000 (b.c.th12"	\	25°C		0.45	0.6	1	
CC	Supply current	LMV822 (both amplifiers)		-40°C to 125°C			0.8	mA	
				25°C		0.72	1		
		LMV824 (all four amplifiers)		-40°C to 125°C			1.2		



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2.7-V ELECTRICAL CHARACTERISTICS (continued)

 $V_{CC+} = 2.7 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 1 \text{ V}$, $V_{O} = 1.35 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
SR	Slew rate ⁽¹⁾		25°C		1.7		V/µs
GBW	Gain bandwidth product	(2)	25°C		5		MHz
Фт	Phase margin	(2)	25°C		60		deg
	Gain margin	(2)	25°C		8.6		dB
	Amplifier-to-amplifier isolation	$V_{CC+} = 5 \text{ V}, R_L = 100 \text{ k}\Omega \text{ to } 2.5 \text{ V}^{(3)}$	25°C		135		dB
V _n	Equivalent input noise voltage	f = 1 kHz, V _{IC} = 1 V	25°C		45		nV/√ Hz
In	Equivalent input noise current	f = 1 kHz	25°C		0.18		pA/√Hz
THD	Total harmonic distortion	$f = 1 \text{ kHz}, A_V = -2, R_L = 10 \text{ k}\Omega,$ $V_O = 4.1 \text{ V}_{p-p}$	25°C		0.01		%

Connected as voltage follower with 1-V step input. Value specified is the slower of the positive and negative slew rates.

⁴⁰⁻dB closed-loop dc gain, $C_L = 22 \text{ pF}$ Each amplifier excited in turn with 1 kHz to produce $V_O = 3 V_{p-p}$



5-V ELECTRICAL CHARACTERISTICS

 V_{CC+} = 5 V, V_{CC-} = 0 V, V_{IC} = 2 V, V_{O} = 2.5 V, and R_{L} > 1 $M\Omega$ (unless otherwise noted)

	PARAMETER	TEST CONDIT	TIONS	T _A	MIN	TYP	MAX	UNIT	
V _{IO}	Input offset voltage			25°C		1	6	mV	
- 10				-40°C to 125°C			6		
α_{VIO}	Average temperature coefficient of input offset voltage			25°C		1		μV/°C	
I _{IB}	Input bias current			25°C		40	100	nA	
ııB	input bias current			-40°C to 125°C			150	ш	
الم	Input offset current			25°C		0.5	30	nA	
I _{IO}	input offset current			-40°C to 125°C			50	ПА	
CMRR	Common-mode rejection ratio	$V_{IC} = 0$ to 4 V		25°C	72	90		dB	
CIVILLIA	Common-mode rejection ratio	AIC = 0 10 4 A		-40°C to 125°C	70			ub	
+k _{SVR}	Positive supply-voltage	$V_{CC+} = 1.7 \text{ V to 4 V, } V_{CC}$	$_{C-} = -1 \text{ V},$	25°C	75	85		dB	
FNSVR	rejection ratio	$V_{O} = 0, V_{IC} = 0$		-40°C to 125°C	70			ub	
k,_	Negative supply-voltage	$V_{CC+} = 1.7 \text{ V}, V_{CC-} = -1$	V to −3.3 V,	25°C	73	85		dB	
-k _{SVR}	rejection ratio	$V_O = 0$, $V_{IC} = 0$		-40°C to 125°C	70			uБ	
V_{ICR}	Common-mode input voltage range	CMRR ≥ 50 dB		25°C	-0.2 to 4.2	-0.3 to 4.3		V	
		$R_L = 600 \Omega \text{ to } 2.5 \text{ V},$	Coursing	25°C	95	105			
		$V_0 = 2.5 \text{ V to } 4.5 \text{ V}$	Sourcing	-40°C to 125°C	90				
		$R_L = 600 \Omega \text{ to } 2.5 \text{ V},$	Cipleina	25°C	95	105		dB	
۸ _V	Lanca di calcalia de la constitución	$V_0 = 2.5 \text{ V to } 0.5 \text{ V}$	Sinking	-40°C to 125°C	90				
	Large-signal voltage amplification	$R_1 = 2 k\Omega \text{ to } 2.5 \text{ V},$	Carraiaa	25°C	95	105			
		$V_0 = 2.5 \text{ V to } 4.5 \text{ V}$	Sourcing	-40°C to 125°C	90				
		$R_L = 2 k\Omega$ to 2.5 V,	Cipleina	25°C	95	105			
		$V_0 = 2.5 \text{ V to } 0.5 \text{ V}$	Sinking	-40°C to 125°C	90				
		V _{CC+} = 5 V,	I Park I accel	25°C	4.75	4.84			
			High level	-40°C to 125°C	4.6				
		$R_L = 600 \Omega \text{ to } 2.5 \text{ V}$	Laurianal	25°C		0.17	0.25		
,	Output auda a		Low level	-40°C to 125°C			0.3	V	
/ ₀	Output swing		High Issuel	25°C	4.85	4.9		V	
		$V_{CC+} = 5 V$,	High level	-40°C to 125°C	4.8				
		$R_L = 2 k\Omega$ to 2.5 V	1	25°C		0.1	0.15	1	
			Low level	-40°C to 125°C			0.2		
		V = 0.V	Coursing	25°C	20	45			
	Output ourrent	$V_O = 0 V$	Sourcing	-40°C to 125°C	15			, A	
lo	Output current	V 5 V	Cialda a	25°C	20	40		mA	
		V _O = 5 V	Sinking	-40°C to 125°C	15				
		LM\/004		25°C		0.3	0.4		
		LMV821		-40°C to 125°C			0.6	5	
	Cupply ourrant	LM\/000 /b - th 1''	.\	25°C		0.5	0.7		
CC		LMV822 (both amplifiers)		-40°C to 125°C			0.9	-	
				25°C		1	1.3		
		LMV824 (all four amplifi	ers)	-40°C to 125°C			1.5		



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5-V ELECTRICAL CHARACTERISTICS (continued)

 $V_{CC+} = 5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 2 \text{ V}$, $V_{O} = 2.5 \text{ V}$, and $R_{I} > 1 \text{ M}\Omega$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
SR	Slew rate	$V_{CC+} = 5 V^{(1)}$	25°C	1.4	1.9		V/µs
GBW	Gain bandwidth product	(2)	25°C		5.5		MHz
Фт	Phase margin	(2)	25°C		64.2		deg
	Gain margin	(2)	25°C		8.7		dB
	Amplifier-to-amplifier isolation	$V_{CC+} = 5 \text{ V}, R_L = 100 \text{ k}\Omega \text{ to } 2.5 \text{ V}^{(3)}$	25°C		135		dB
V _n	Equivalent input noise voltage	f = 1 kHz, V _{IC} = 1 V	25°C		42		nV/√ Hz
In	Equivalent input noise current	f = 1 kHz	25°C		0.2		pA/√ Hz
THD	Total harmonic distortion	$f = 1 \text{ kHz}, A_V = -2, R_L = 10 \text{ k}\Omega,$ $V_O = 4.1 V_{p-p}$	25°C		0.01		%

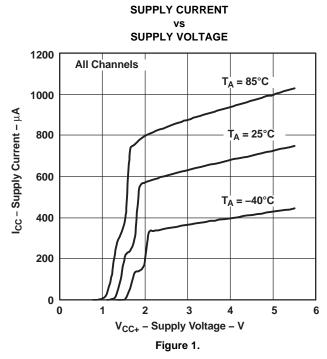
Connected as voltage follower with 3-V step input. Value specified is the slower of the positive and negative slew rates.

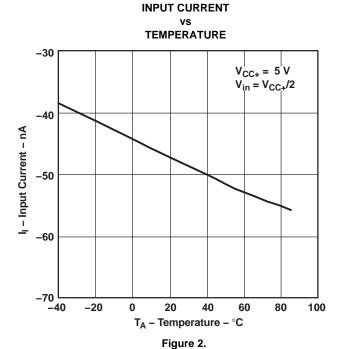
⁴⁰⁻dB closed-loop dc gain, $C_L = 22 \text{ pF}$ Each amplifier excited in turn with 1 kHz to produce $V_O = 3 V_{p-p}$



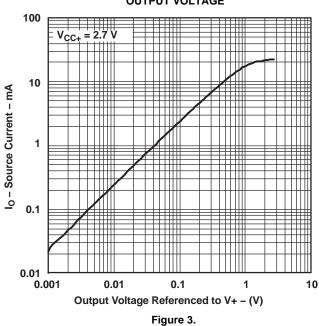
TYPICAL CHARACTERISTICS

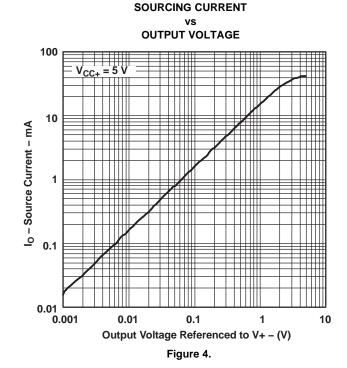
 $T_A = 25$ °C, $V_{CC+} = 5$ -V single supply (unless otherwise noted)





SOURCING CURRENT vs **OUTPUT VOLTAGE** 100 10







ISTRUMENTS

TYPICAL CHARACTERISTICS (continued)

 $T_A = 25$ °C, $V_{CC+} = 5$ -V single supply (unless otherwise noted)

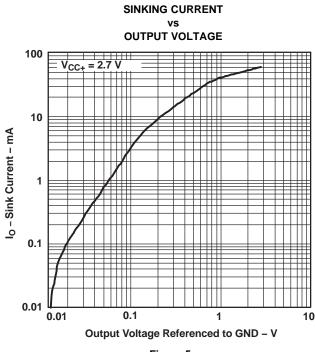


Figure 5.

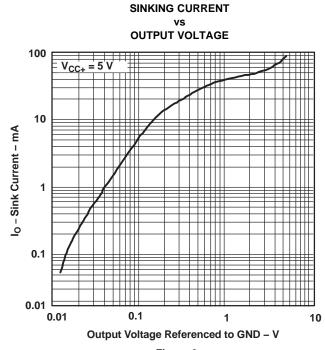
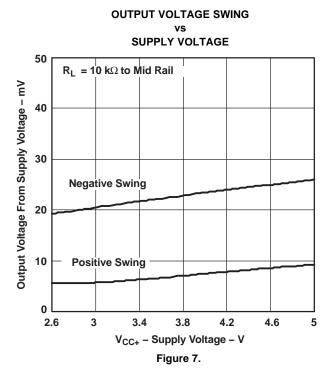
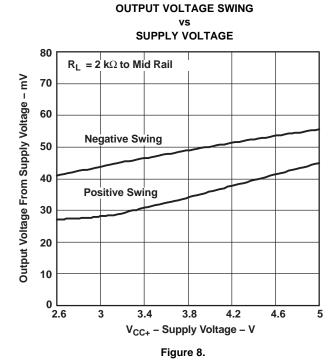


Figure 6.

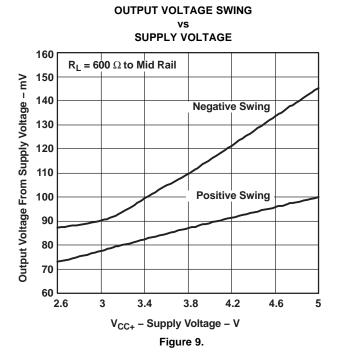




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 $T_A = 25$ °C, $V_{CC+} = 5$ -V single supply (unless otherwise noted)



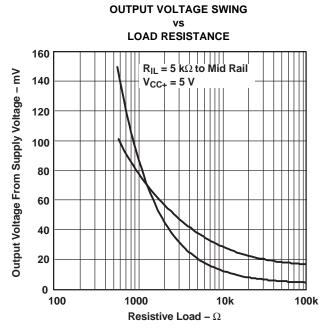
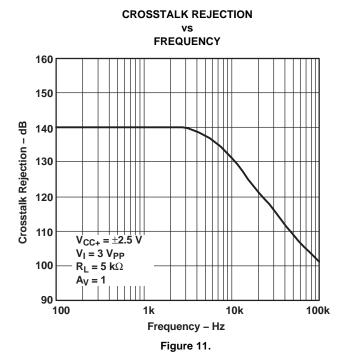
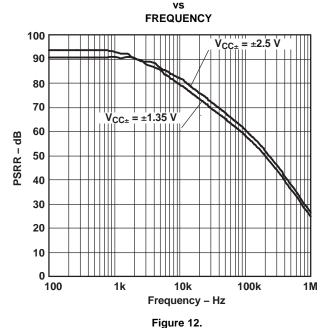


Figure 10.

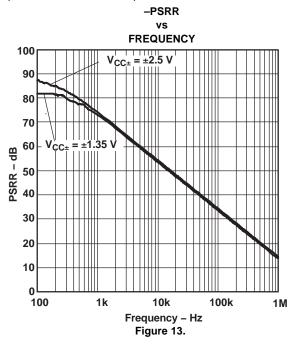




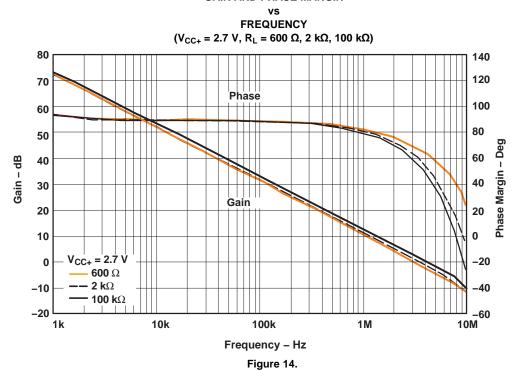
+PSRR



 $T_A = 25$ °C, $V_{CC+} = 5$ -V single supply (unless otherwise noted)



GAIN AND PHASE MARGIN





 $T_A = 25$ °C, $V_{CC+} = 5$ -V single supply (unless otherwise noted)

GAIN AND PHASE MARGIN

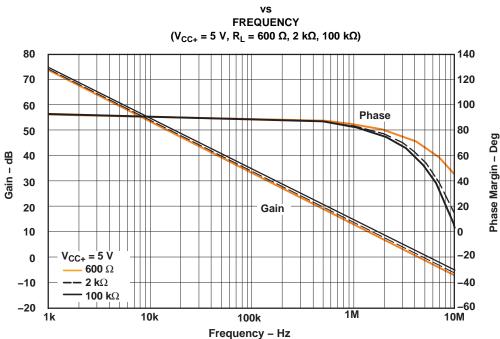
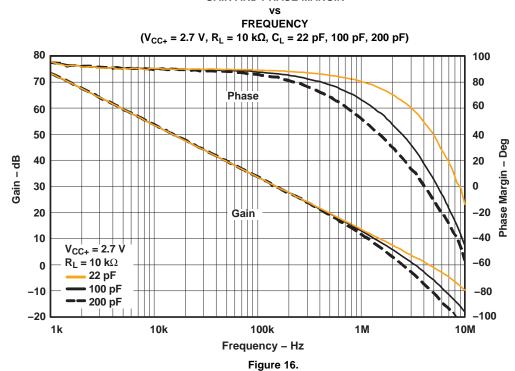


Figure 15.

GAIN AND PHASE MARGIN



NSTRUMENTS

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TYPICAL CHARACTERISTICS (continued)

 $T_A = 25$ °C, $V_{CC+} = 5$ -V single supply (unless otherwise noted)

GAIN AND PHASE MARGIN

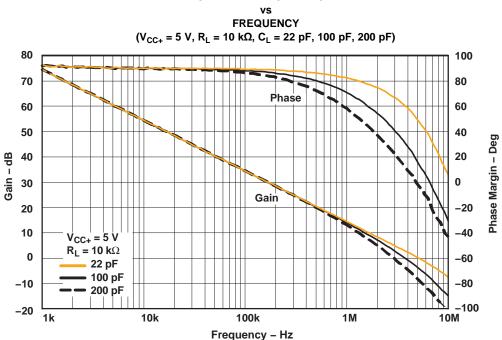


Figure 17.

GAIN AND PHASE MARGIN

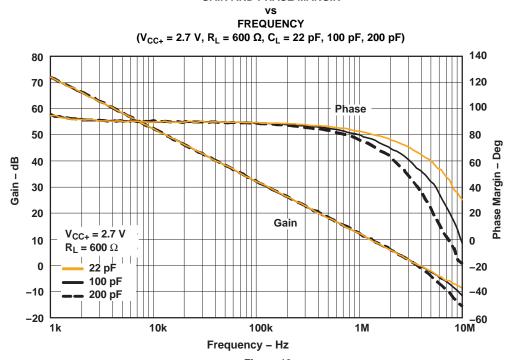


Figure 18.



 $T_A = 25$ °C, $V_{CC+} = 5$ -V single supply (unless otherwise noted)

GAIN AND PHASE MARGIN

vs FREQUENCY ($V_{CC+}=5~V,~R_L=600~\Omega,~C_L=22~pF,~100~pF,~200~pF$)

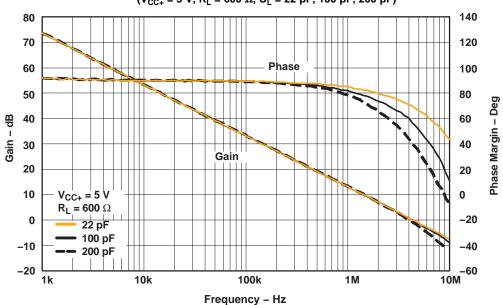


Figure 19.





17-Aug-2012

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
LMV821QDBVRQ1	ACTIVE	SOT-23	DBV	5		TBD	Call TI	Call TI	
LMV822QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
LMV824QDRQ1	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
LMV824QPWRQ1	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder humps used between the die and package, or 2) lead-based die adhesive used between

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF LMV821-Q1, LMV822-Q1, LMV824-Q1:





17-Aug-2012

● Catalog: LMV821, LMV822, LMV824

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

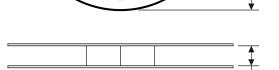
PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV824QPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
LMV824QPWRQ1	TSSOP	PW	14	2000	367.0	367.0	35.0	

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-178 Variation AA.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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